

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (Ultra High speed U-MOSIII)

# TPCP8003-H

High Efficiency DC/DC Converter Applications

Notebook PC Applications

Portable Equipment Applications

- Small footprint due to a small and thin package
- High speed switching
- Small gate charge:  $Q_{SW} = 7.5 \text{ nC} (\text{typ.})$
- Low drain-source ON-resistance:  $R_{DS(\text{ON})} = 130 \text{ m}\Omega (\text{typ.})$
- High forward transfer admittance:  $|Y_{fs}| = 5.4 \text{ S} (\text{typ.})$
- Low leakage current:  $I_{DSS} = 10 \mu\text{A} (\text{max}) (\text{V}_{DS} = 100\text{V})$
- Enhancement mode:  $V_{th} = 1.1 \text{ to } 2.3 \text{ V} (\text{V}_{DS} = 10 \text{ V}, I_D = 1\text{mA})$

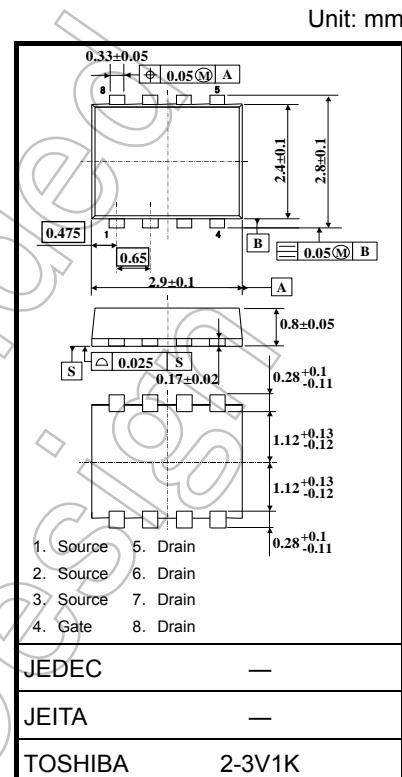
## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Characteristic	Symbol	Rating	Unit	
Drain-source voltage	$V_{DSS}$	100	V	
Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )	$V_{DGR}$	100	V	
Gate-source voltage	$V_{GSS}$	$\pm 20$	V	
Drain current	DC (Note 1)	$I_D$	2.2	A
	Pulsed (Note 1)	$I_{DP}$	8.8	
Drain power dissipation ( $t = 5 \text{ s}$ )	$P_D$	1.68	W	
(Note 2a)				
Drain power dissipation ( $t = 5 \text{ s}$ )	$P_D$	0.84	W	
(Note 2b)				
Single-pulse avalanche energy	$E_{AS}$	3.93	mJ	
(Note 3)				
Avalanche current	$I_{AR}$	2.2	A	
Repetitive avalanche energy	$E_{AR}$	0.016	mJ	
( $T_c=25^\circ\text{C}$ ) (Note 4)				
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$	
Storage temperature range	$T_{stg}$	-55 to 150	$^\circ\text{C}$	

Note: For Notes 1 to 4, refer to the next page.

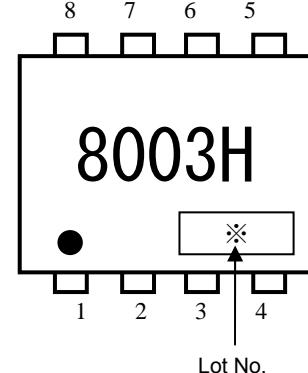
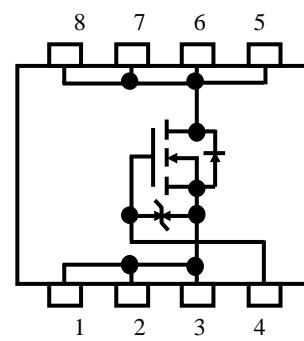
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.017 g (typ.)

## Circuit Configuration



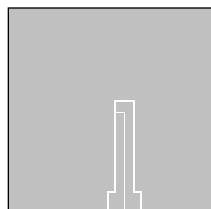
Lot No.

## Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to ambient ( $t = 5$ s) (Note 2a)	$R_{th}$ (ch-a)	74.4	°C/W
Thermal resistance, channel to ambient ( $t = 5$ s) (Note 2b)	$R_{th}$ (ch-a)	148.8	°C/W

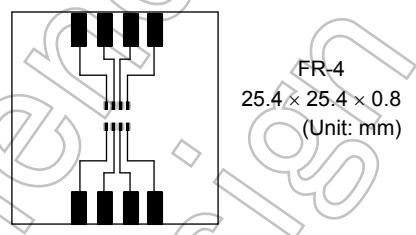
Note 1: The channel temperature should not exceed 150°C during use.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



(a)

FR-4  
25.4 × 25.4 × 0.8  
(Unit: mm)



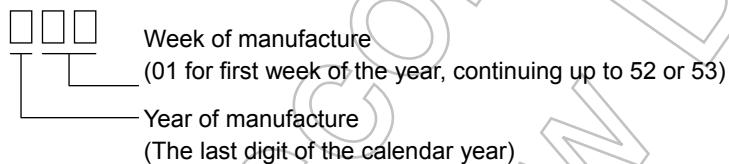
(b)

FR-4  
25.4 × 25.4 × 0.8  
(Unit: mm)

Note 3:  $V_{DD} = 24$  V,  $T_{Ch} = 25^\circ\text{C}$  (initial),  $L = 1$  mH,  $R_G = 1 \Omega$ ,  $I_{AR} = 2.2\text{A}$

Note 4: Repetitive rating: pulse width limited by max channel temperature

Note 5: \* Weekly code: (Three digits)

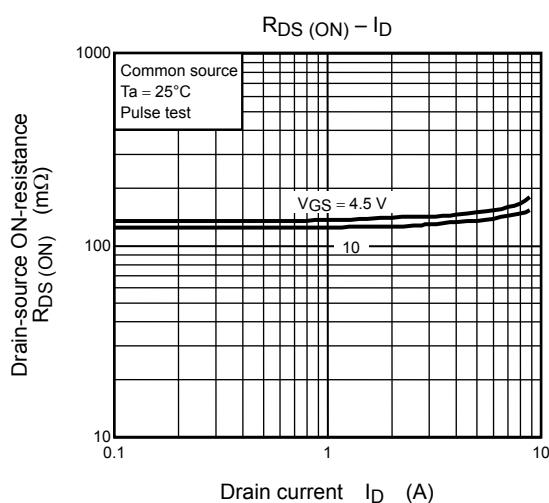
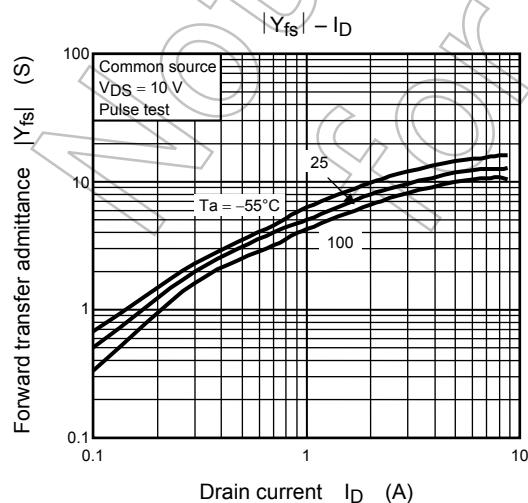
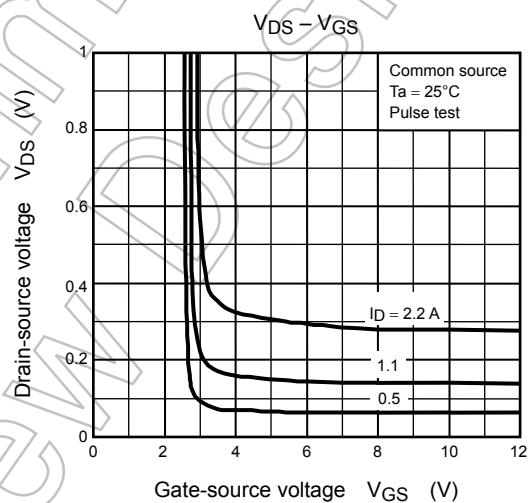
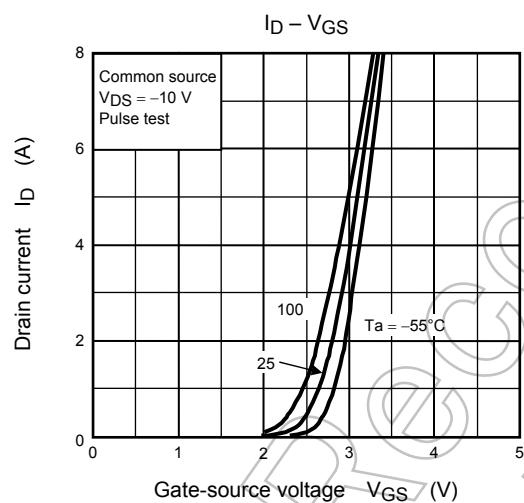
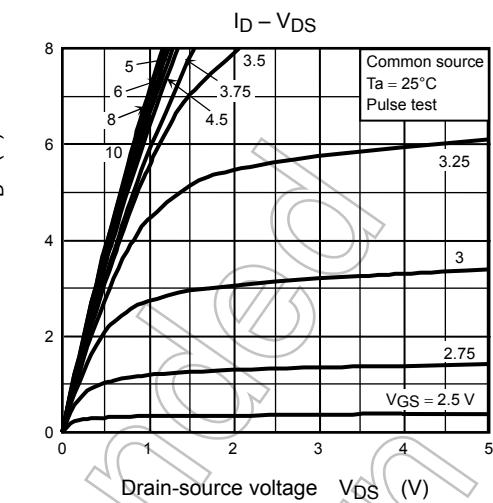
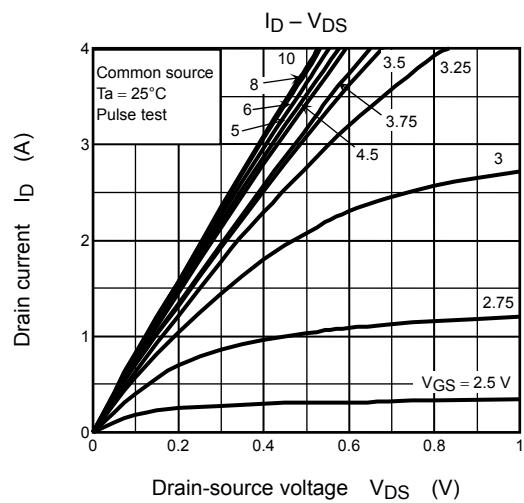


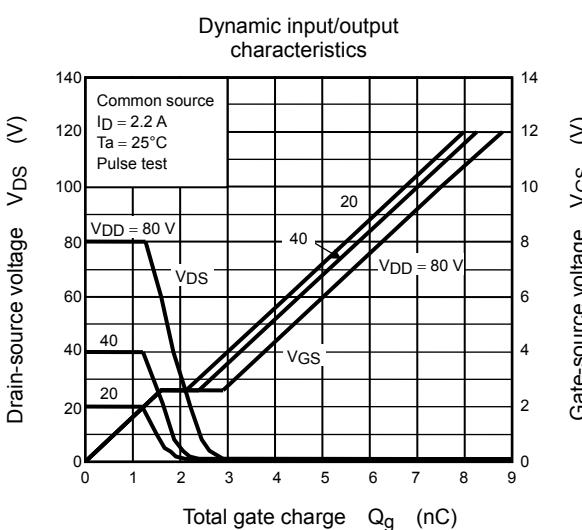
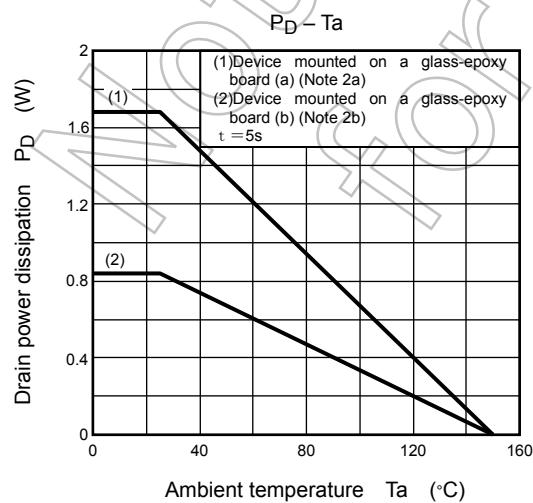
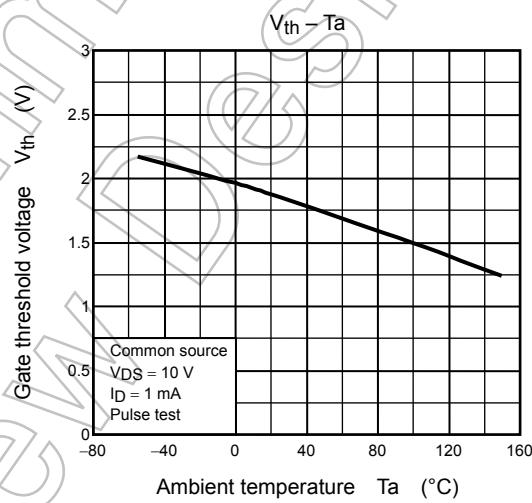
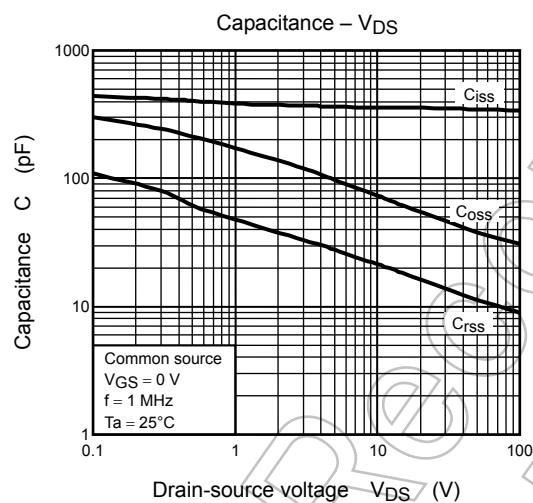
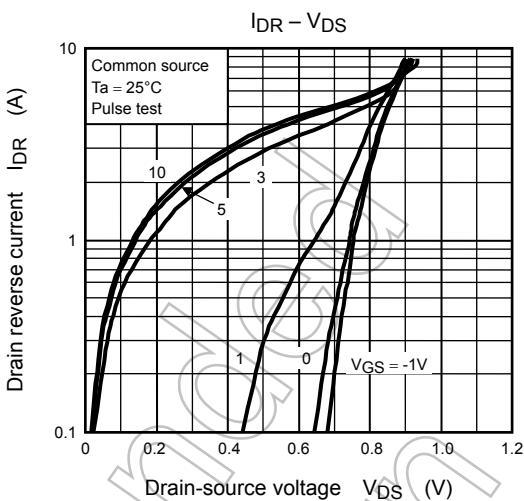
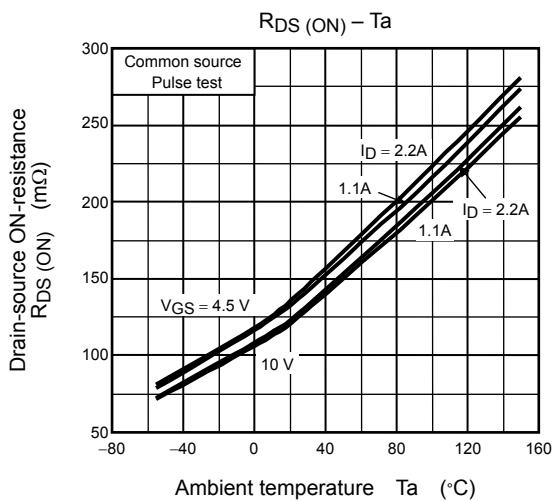
Electrical Characteristics ( $T_a = 25^\circ C$ )

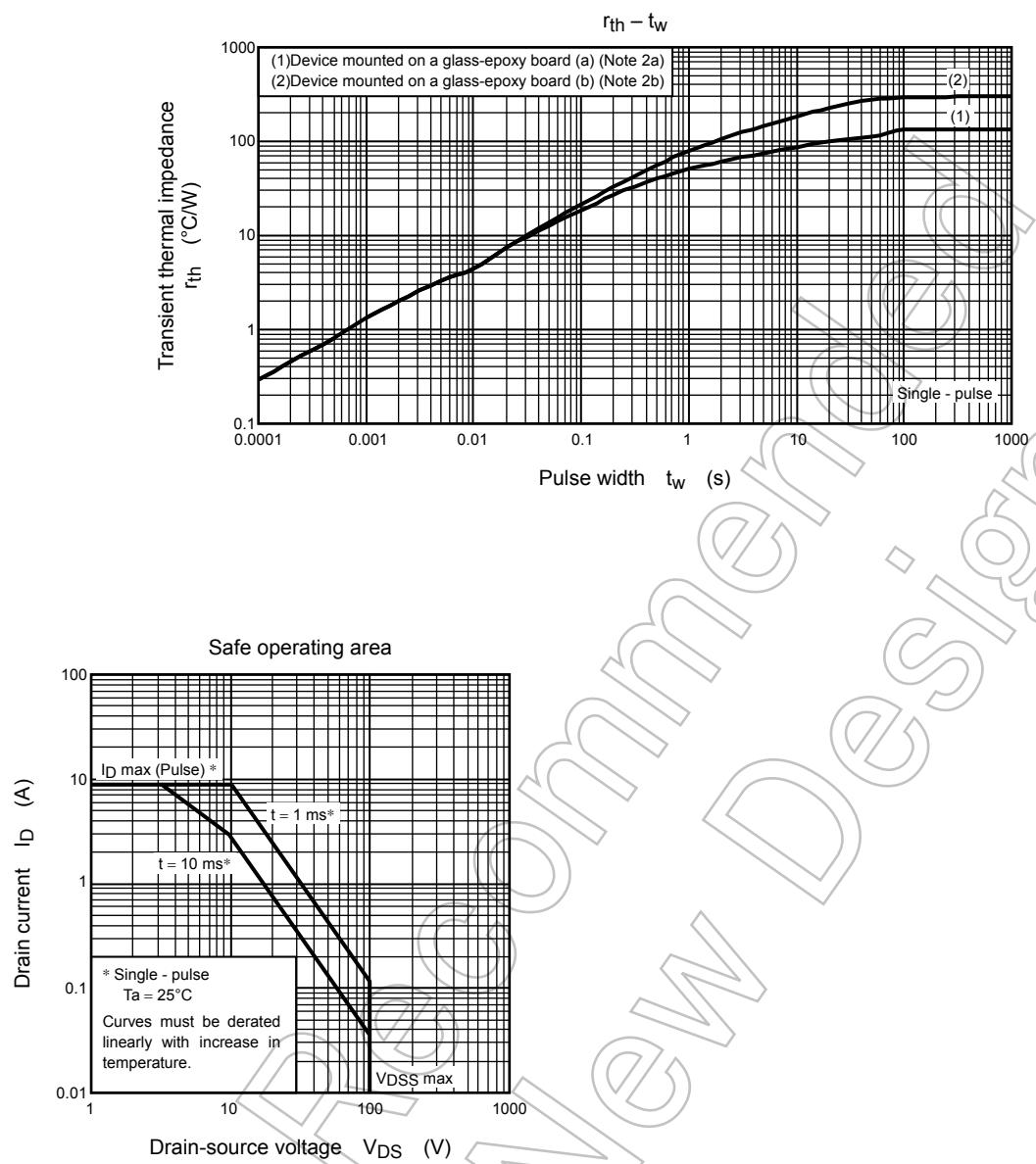
Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 16 V, V_{DS} = 0 V$	—	—	$\pm 10$	$\mu A$
Drain cutoff current	$I_{DSS}$	$V_{DS} = 100 V, V_{GS} = 0 V$	—	—	10	$\mu A$
Drain-source breakdown voltage	$V_{(BR) DSS}$	$I_D = 10 mA, V_{GS} = 0 V$	100	—	—	V
	$V_{(BR) DSX}$	$I_D = 10 mA, V_{GS} = -20 V$	60	—	—	
Gate threshold voltage	$V_{th}$	$V_{DS} = 10 V, I_D = 1 mA$	1.1	—	2.3	V
Drain-source ON-resistance	$R_{DS (ON)}$	$V_{GS} = 4.5 V, I_D = 1.1 A$	—	140	190	$m\Omega$
		$V_{GS} = 10 V, I_D = 1.1 A$	—	130	180	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10 V, I_D = 1.1 A$	2.7	5.4	—	S
Input capacitance	$C_{iss}$	$V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz$	—	360	—	pF
Reverse transfer capacitance	$C_{rss}$		—	22	—	
Output capacitance	$C_{oss}$		—	75	—	
Switching time	Rise time	$t_r$		—	7	ns
	Turn-on time	$t_{on}$		—	14	
	Fall time	$t_f$		—	3	
	Turn-off time	$t_{off}$		—	17	
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} = 80 V, V_{GS} = 10 V, I_D = 2.2 A$	—	7.5	—	nC
		$V_{DD} = 80 V, V_{GS} = 5 V, I_D = 2.2 A$	—	4.5	—	
Gate-source charge 1	$Q_{gs1}$	$V_{DD} = 80 V, V_{GS} = 10 V, I_D = 2.2 A$	—	1.6	—	nC
Gate-drain ("Miller") charge	$Q_{gd}$		—	1.3	—	
Gate switch charge	$Q_{SW}$		—	2.0	—	

Source-Drain Ratings and Characteristics ( $T_a = 25^\circ C$ )

Characteristic	Symbol	Test Condition	Min	Typ.	Max	Unit
Drain reverse current (Pulse (Note 1))	$I_{DRP}$	—	—	—	8.8	A
Forward voltage (diode)	$V_{DSF}$	$I_{DR} = 2.2 A, V_{GS} = 0 V$	—	—	-1.2	V







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